

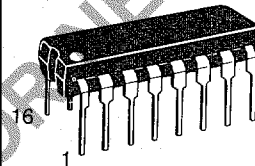
**MOTOROLA****SEMICONDUCTORS**

P.O. BOX 20912 • PHOENIX, ARIZONA 85036

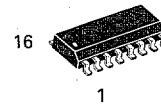
**HIGH VOLTAGE, HIGH CURRENT
DARLINGTON TRANSISTOR ARRAYS**

The seven NPN Darlington connected transistors in these arrays are well suited for driving lamps, relays, or printer hammers in a variety of industrial and consumer applications. Their high breakdown voltage and internal suppression diodes insure freedom from problems associated with inductive loads. Peak inrush currents to 600 mA permit them to drive incandescent lamps.

The MC1411,B device is a general purpose array for use with DTL, TTL, PMOS, or CMOS Logic. The MC1412,B contains a zener diode and resistor in series with the input to limit input current for use with 14 to 25 Volt PMOS Logic. The MC1413,B with a 2.7 k Ω series input resistor is well suited for systems utilizing a 5 Volt TTL or CMOS Logic. The MC1416,B uses a series 10.5 k Ω resistor and is useful in 8 to 18 Volt MOS systems.

**PERIPHERAL
DRIVER ARRAYS****SILICON MONOLITHIC
INTEGRATED CIRCUITS**

P SUFFIX
PLASTIC PACKAGE
CASE 648-06



D SUFFIX
PLASTIC PACKAGE
CASE 751B-03
SO-16

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ and rating apply to any one device in the package unless otherwise noted.)

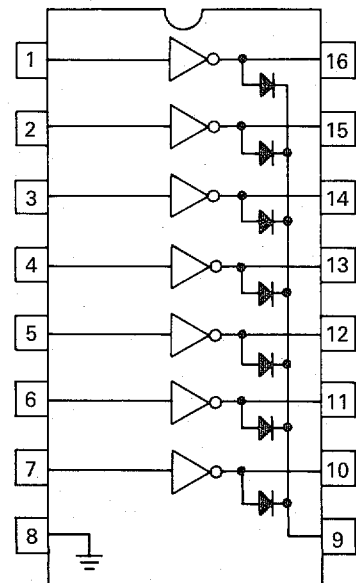
Rating	Symbol	Value	Unit
Output Voltage	V_O	50*	V
Input Voltage (Except MC1411)	V_I	30	V
Collector Current — Continuous	I_C	500	mA
Base Current — Continuous	I_B	25	mA
Operating Ambient Temperature Range MC1411-16 MC1411B-16B	T_A	-20 to +85 -40 to +85	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$
Junction Temperature	T_J	150	$^\circ\text{C}$

Maximum Package Power Dissipation (See Thermal Information Section)

*Higher voltage selection available. See your local representative.

ORDERING INFORMATION

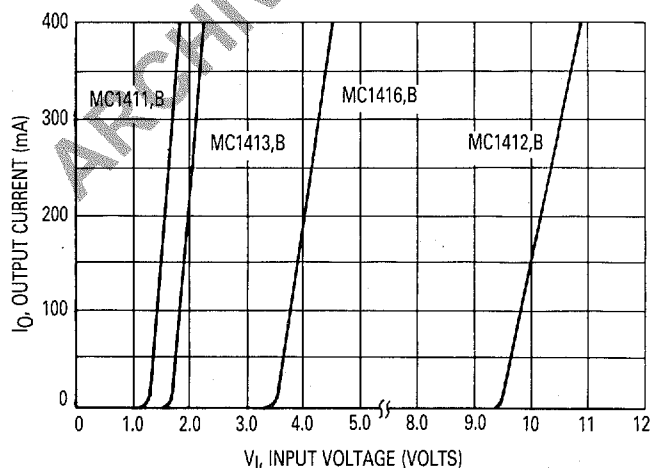
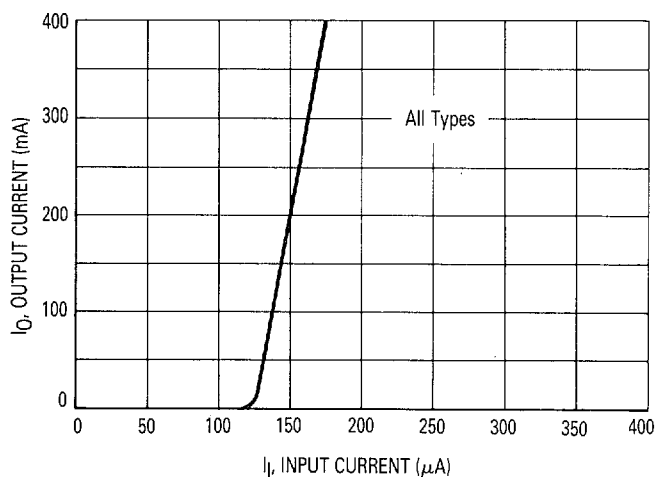
MC1411P (ULN2001A)	MC1411D	} -20° to +85°C
MC1412P (ULN2002A)	MC1412D	
MC1413P (ULN2003A)	MC1413D	
MC1416P (ULN2004A)	MC1416D	
MC1411BP (ULQ2001A)	MC1411BD	} -40° to +85°C
MC1412BP (ULQ2002A)	MC1412BD	
MC1413BP (ULQ2003A)	MC1413BD	
MC1416BP (ULQ2004A)	MC1416BD	

PIN CONNECTIONS

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
Output Leakage Current (* $V_O = 50\text{ V}$, $T_A = +85^\circ\text{C}$) (* $V_O = 50\text{ V}$, $T_A = +25^\circ\text{C}$) (* $V_O = 50\text{ V}$, $T_A = +85^\circ\text{C}$, $V_I = 6.0\text{ V}$) (* $V_O = 50\text{ V}$, $T_A = +85^\circ\text{C}$, $V_I = 1.0\text{ V}$)	All Types All Types MC1412,B MC1416,B	I_{CEX}	—	—	100 50 500 500	μA
Collector-Emitter Saturation Voltage ($I_C = 350\text{ mA}$, $I_B = 500\text{ }\mu\text{A}$) ($I_C = 200\text{ mA}$, $I_B = 350\text{ }\mu\text{A}$) ($I_C = 100\text{ mA}$, $I_B = 250\text{ }\mu\text{A}$)	All Types All Types All Types	$V_{CE(sat)}$	—	1.1 0.95 0.85	1.6 1.3 1.1	V
Input Current — On Condition ($V_I = 17\text{ V}$) ($V_I = 3.85\text{ V}$) ($V_I = 5.0\text{ V}$) ($V_I = 12\text{ V}$)	MC1412,B MC1413,B MC1416,B MC1416,B	$I_{I(on)}$	—	0.85 0.93 0.35 1.0	1.3 1.35 0.5 1.45	mA
Input Voltage — On Condition ($V_{CE} = 2.0\text{ V}$, $I_C = 300\text{ mA}$) ($V_{CE} = 2.0\text{ V}$, $I_C = 200\text{ mA}$) ($V_{CE} = 2.0\text{ V}$, $I_C = 250\text{ mA}$) ($V_{CE} = 2.0\text{ V}$, $I_C = 300\text{ mA}$) ($V_{CE} = 2.0\text{ V}$, $I_C = 125\text{ mA}$) ($V_{CE} = 2.0\text{ V}$, $I_C = 200\text{ mA}$) ($V_{CE} = 2.0\text{ V}$, $I_C = 275\text{ mA}$) ($V_{CE} = 2.0\text{ V}$, $I_C = 350\text{ mA}$)	MC1412,B MC1413,B MC1413,B MC1413,B MC1416,B MC1416,B MC1416,B MC1416,B	$V_{I(on)}$	—	—	13 2.4 2.7 3.0 5.0 6.0 7.0 8.0	V
Input Current — Off Condition ($I_C = 500\text{ }\mu\text{A}$, $T_A = +85^\circ\text{C}$)	All Types	$I_{I(off)}$	50	100	—	μA
DC Current Gain ($V_{CE} = 2.0\text{ V}$, $I_C = 350\text{ mA}$)	MC1411,B	h_{FE}	1000	—	—	—
Input Capacitance		C_i	—	15	30	pF
Turn-On Delay Time (50% E_I to 50% E_O)		t_{on}	—	0.25	1.0	μs
Turn-Off Delay Time (50% E_I to 50% E_O)		t_{off}	—	0.25	1.0	μs
Clamp Diode Leakage Current ($V_R = 50\text{ V}$)	$T_A = +25^\circ\text{C}$ $T_A = +85^\circ\text{C}$	I_R	—	—	50 100	μA
Clamp Diode Forward Voltage ($I_F = 350\text{ mA}$)		V_F	—	1.5	2.0	V

*Higher voltage selections available, contact your local representative.

TYPICAL PERFORMANCE CURVES — $T_A = 25^\circ\text{C}$ **FIGURE 1 — OUTPUT CURRENT versus INPUT VOLTAGE****FIGURE 2 — OUTPUT CURRENT versus INPUT CURRENT**

TYPICAL CHARACTERISTIC CURVES — $T_A = 25^\circ\text{C}$ (continued)

FIGURE 3 — TYPICAL OUTPUT CHARACTERISTICS

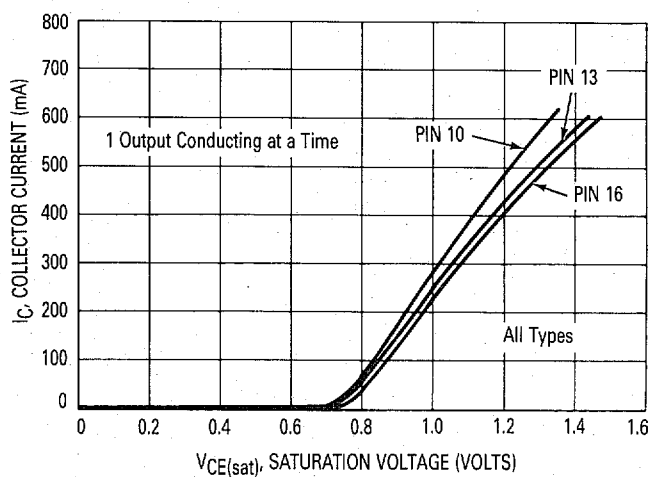


FIGURE 4 — INPUT CHARACTERISTICS — MC1412,B

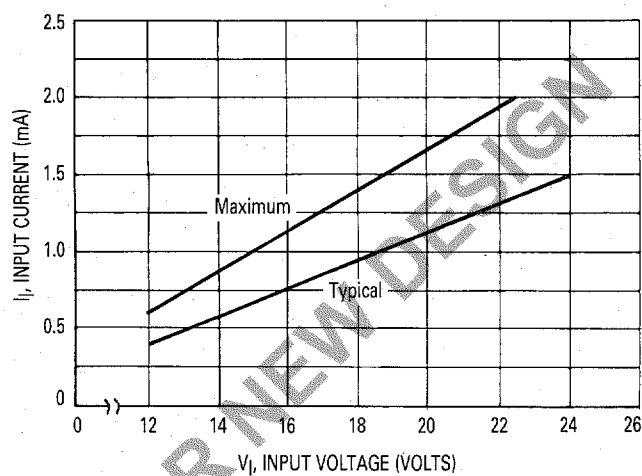


FIGURE 5 — INPUT CHARACTERISTICS — MC1413,B

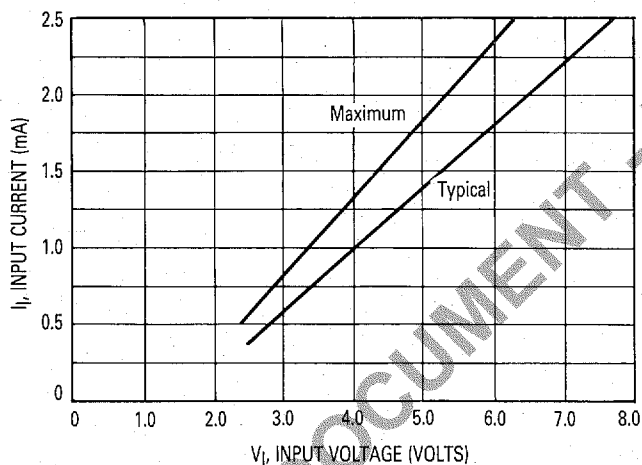
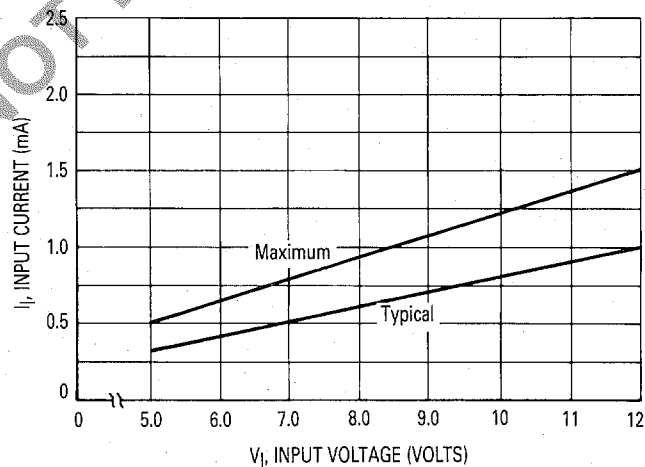
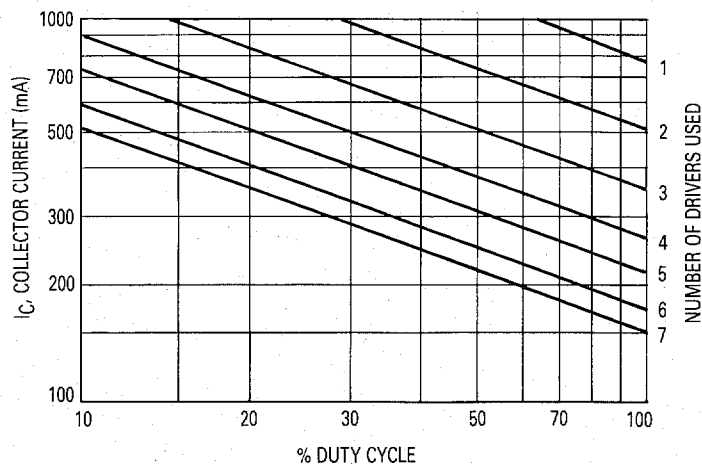
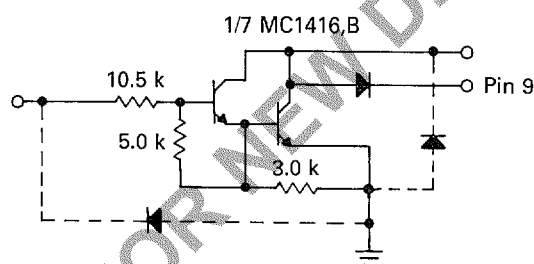
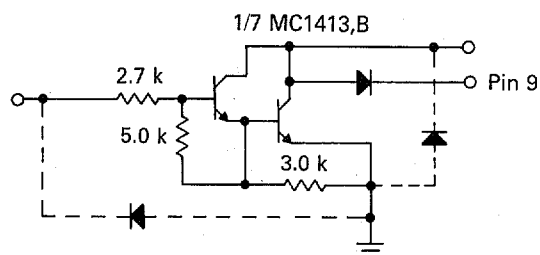
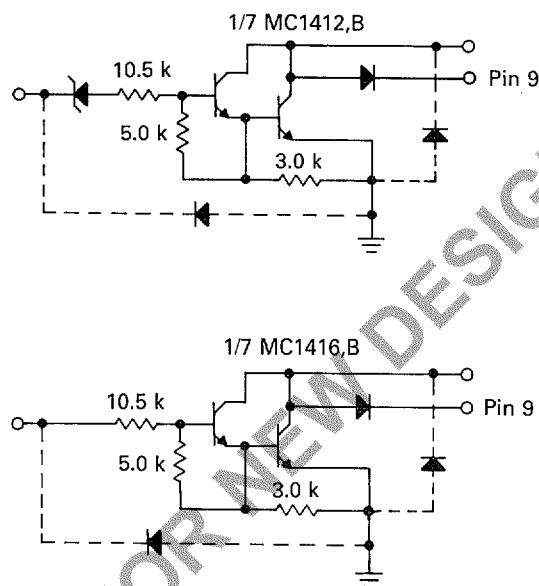
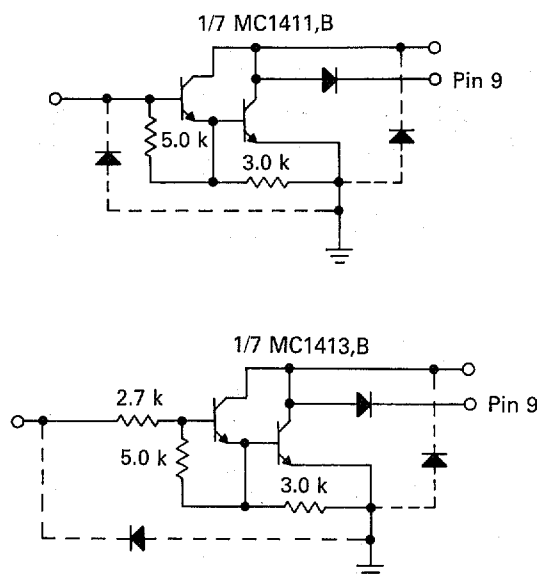


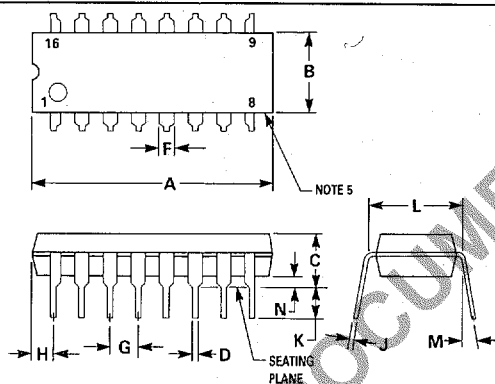
FIGURE 6 — INPUT CHARACTERISTICS — MC1416,B

FIGURE 7 — MAXIMUM COLLECTOR CURRENT
versus DUTY CYCLE
(AND NUMBER OF DRIVERS IN USE)

REPRESENTATIVE CIRCUIT SCHEMATICS



OUTLINE DIMENSIONS



NOTES:

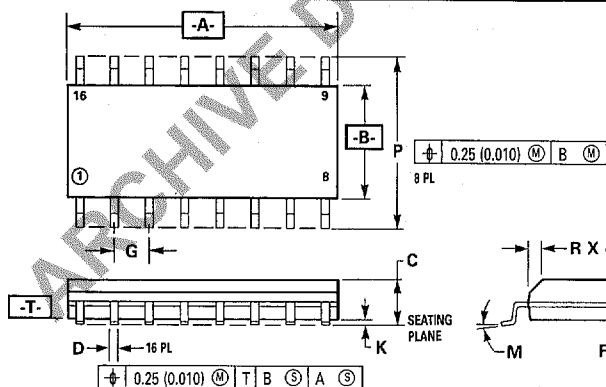
1. LEADS WITHIN 0.13 mm (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
2. DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIMENSION "B" DOES NOT INCLUDE MOLD FLASH.
4. "F" DIMENSION IS FOR FULL LEADS.
5. ROUNDED CORNERS OPTIONAL.

P SUFFIX

PLASTIC PACKAGE
CASE 648-06

$R_{\theta JA} = 67^{\circ}\text{C/W (TYP)}$

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	18.80	21.34	0.740	0.840
B	6.10	6.60	0.240	0.260
C	3.69	4.69	0.145	0.185
D	0.38	0.53	0.015	0.021
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.38	2.41	0.015	0.095
J	0.20	0.38	0.008	0.015
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	0°	10°	0°	10°
N	0.39	1.01	0.015	0.040



NOTES:

1. DIMENSIONS A AND B ARE DATUMS AND T IS A DATUM SURFACE.
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
3. CONTROLLING DIMENSION: MILLIMETER.
4. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
5. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

D SUFFIX

PLASTIC PACKAGE
CASE 751B-03

$R_{\theta JA} = 135^{\circ}\text{C/W (TYP)}$

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

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